

NSN 5961-01-009-6319 Diode Semiconductor Device - Page 1 of 1
View Online at https://aerobasegroup.com/nsn/5961-01-009-631
Inclosure Material:
Glass and metal
Overall Length:
0.230 inches
Terminal Length:
1.000 inches
Overall Diameter:
0.185 inches
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.187 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
18.0 regulator voltage
Current Rating Per Characteristic:
130.00 milliamperes repetitive peak forward current
Power Rating Per Characteristic:
6.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:

Unit Of Measure:

Demilitarization:

No

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